

TOSHIBA MOS DIGITAL INTEGRATED CIRCUIT SILICON GATE CMOS

524,288-WORD BY 18-BIT SYNCHRONOUS NO-TURNAROUND STATIC RAM

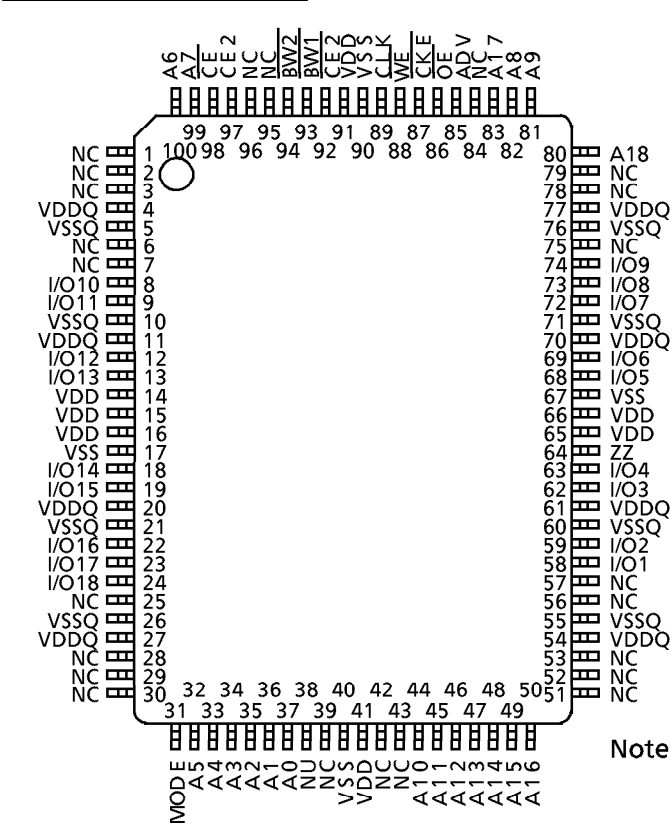
DESCRIPTION

The TC55VD818FF is a synchronous static random access memory(SRAM) organized as 524,288 words by 18 bits. NtRAM™(no-turnaround) SRAM offers high bandwidth by eliminating dead cycles during the transition from a read to a write and vice versa. All inputs except Output Enable OE and the Snooze pin ZZ are synchronized with the rising edge of the CLK input. A Read operation is initiated by the ADV Address Advanced Input signal ; the input from the address pins and all control pins except the OE and ZZ pins are loaded into the internal registers on the rising edge of CLK in the cycle in which ADV is asserted. The output data is available two clock cycles later. Write operations are internally self-timed and are initiated by the rising edge of CLK in the cycle in which ADV is asserted. The input from the address pins and all control pins except the OE and ZZ pins are loaded into the internal registers on the rising edge of CLK in the cycle in which ADV is asserted. Input data is loaded in the third cycle after the cycle in which ADV is asserted. Byte Write Enables(BW1 to BW2) allow from one to four Byte Write operations to be performed. A 2-bit burst address counter and control logic are integrated into this SRAM. The TC55VD818FF uses a single power supply (3.3V) or dual power supplies(3.3V for core and 2.5V for output buffer) and is available in a 100-pin low-profile plastic QFP(LQFP).

FEATURES

- Organized as 524,288 words by 18 bits
- Fast cycle time of 6.6 ns minimum (150 MHz maximum)
- Fast access time of 3.8 ns maximum (from clock edge to data output)
- No-turnaround operation with pipeline data output
- 2-bit burst address counter (support for interleaved or linear burst sequences)
- Synchronous self-timed Write
- Byte Write control
- Snooze mode pin (ZZ) for power down
- LVTTL-compatible interface
- Single power supply (3.3 V) or Dual power supplies(3.3V for core and 2.5V for output buffer)
- Available in 100-pin LQFP package (LQFP100-P-1420-0.65K ; pitch:0.65 mm, height:1.6 mm, weight:0.56 grams(typical))

PIN ASSIGNMENT (TOP VIEW)



PIN NAMES

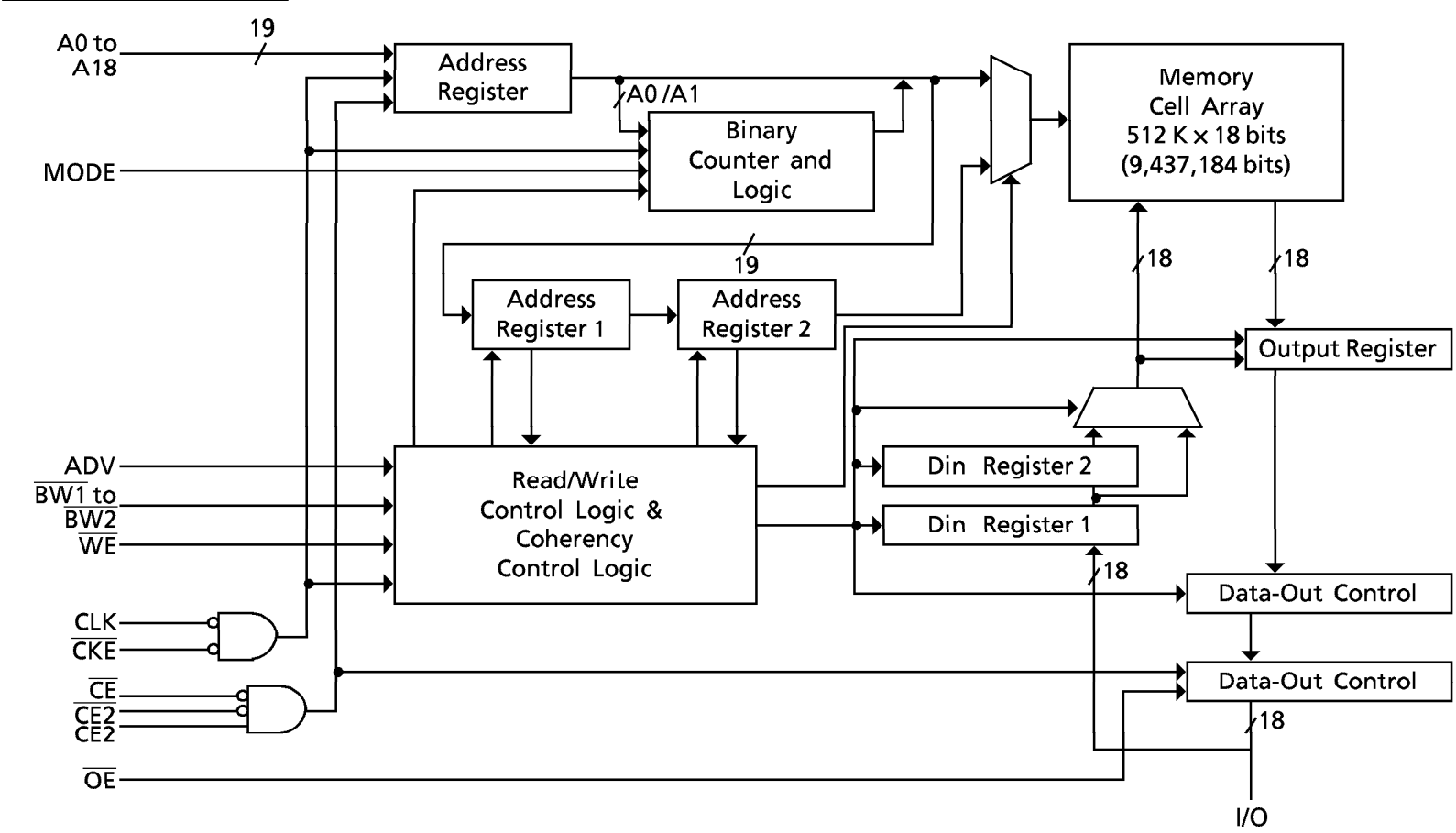
|               |                                |
|---------------|--------------------------------|
| CLK           | Clock Input                    |
| A0 to A18     | Address Inputs                 |
| CE, CE2, CE2  | Chip Enable Inputs             |
| OE            | Output Enable                  |
| WE            | Write Enable Input             |
| BW1 to BW2    | Byte Write Enable              |
| ADV           | Address Advance Input          |
| CKE           | Clock Enable                   |
| ZZ            | Snooze Input                   |
| I/O1 to I/O18 | Data Inputs/Outputs            |
| MODE          | Mode Select Input              |
| NC            | Not Connected                  |
| NU            | Not Usable                     |
| VDD           | Power Supply for Core          |
| VDDQ          | Power Supply for Output Buffer |
| VSS           | Ground for Core                |
| VSSQ          | Ground for Output Buffer       |

Note : NtRAM™ and No-Turnaround Random Access Memory are trademarks of Samsung Electronics Co., Ltd.. The architecture and functionality are supported by Samsung and NEC.

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BLOCK DIAGRAM



PIN DESCRIPTIONS

| PIN NUMBER                                                                        | SYMBOL                               | TYPE                    | DESCRIPTION                                                                                                                                                                                                                                                                                                     |
|-----------------------------------------------------------------------------------|--------------------------------------|-------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 89                                                                                | CLK                                  | Input<br>(NA)           | <b>Clock Input</b><br>All synchronous input signals are registered on the rising edge of CLK. When the chip is enabled, address inputs and control pins except for $\overline{OE}$ and ZZ must meet the specified setup and hold times with respect to the CLK rising edge.                                     |
| 37, 36, 35, 34, 33, 32,<br>100, 99, 82, 81, 44, 45,<br>46, 47, 48, 49, 50, 83, 80 | A0 to A18                            | Input<br>(synchronous)  | <b>Address Inputs</b><br>These address inputs are registered on the rising edge of CLK. When the chip is enabled, address inputs must meet the specified setup and hold times with respect to the CLK rising edge.                                                                                              |
| 98                                                                                | $\overline{CE}$                      | Input<br>(synchronous)  | <b>Chip Enable Input</b><br>This active-Low signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded.                                                                                                                                                    |
| 92                                                                                | $\overline{CE2}$                     | Input<br>(synchronous)  | <b>Chip Enable Input</b><br>This active-Low signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded.                                                                                                                                                    |
| 97                                                                                | CE2                                  | Input<br>(synchronous)  | <b>Chip Enable Input</b><br>This active-high signal controls the chip status (enabled or disabled). It is sampled only when a new external address is loaded.                                                                                                                                                   |
| 86                                                                                | $\overline{OE}$                      | Input<br>(asynchronous) | <b>Output Enable Input</b><br>This active-Low signal controls all 18 bits of the I/O output buffer.                                                                                                                                                                                                             |
| 88                                                                                | $\overline{WE}$                      | Input<br>(synchronous)  | <b>Write Enable Input</b><br>This active-Low input controls Read/Write operations.                                                                                                                                                                                                                              |
| 93, 94                                                                            | $\overline{BW1}$ to $\overline{BW2}$ | Input<br>(synchronous)  | <b>Byte Write Enable</b><br>These active-Low inputs control Byte Write operations when a Write cycle is active. A Byte Write pin controls I/O pins as follows.<br>$\overline{BW1}$ : I/O1 to I/O9<br>$\overline{BW2}$ : I/O10 to I/O18                                                                          |
| 85                                                                                | ADV                                  | Input<br>(synchronous)  | <b>Address Advance Input</b><br>This is used to load the internal registers with the input from the address and control signals when it is Low on the rising edge of CLK. When it is High, the internal burst address counter is incremented. The external address inputs are ignored when this signal is High. |
| 87                                                                                | $\overline{CKE}$                     | Input<br>(synchronous)  | <b>Clock Enable</b><br>When High, CLK input is ignored and outputs retain the same state.                                                                                                                                                                                                                       |

| PIN NUMBER                                                                            | SYMBOL           | TYPE                    | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                             |
|---------------------------------------------------------------------------------------|------------------|-------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 64                                                                                    | ZZ               | Input<br>(asynchronous) | <b>Snooze Input</b><br>This active-High signal is used to place the device into Sleep Mode (Low-Power Standby Mode). When Low, the device remains in the Active state. When High, the device goes into the Sleep state and memory data is retained. After this signal has been de-asserted, the device will wake up when a read or write operation is initiated by ADV. |
| 58, 59, 62, 63, 68, 69, 72, 73, 74, 8, 9, 12, 13, 18, 19, 22, 23, 24                  | I/O1 to I/O18    | I/O<br>(synchronous)    | <b>Data Input/Output</b>                                                                                                                                                                                                                                                                                                                                                |
| 31                                                                                    | MODE             | Input<br>(synchronous)  | <b>Mode Select Input</b><br>This signal selects the burst sequence. When High, the burst sequence is interleaved. When Low, it is linear.                                                                                                                                                                                                                               |
| 1, 2, 3, 6, 7, 25, 28, 29, 30, 39, 42, 43, 51, 52, 53, 56, 57, 75, 78, 79, 84, 95, 96 | NC               | NC                      | <b>Not Connected</b>                                                                                                                                                                                                                                                                                                                                                    |
| 38                                                                                    | NU               | Input<br>(asynchronous) | <b>Not Usable</b>                                                                                                                                                                                                                                                                                                                                                       |
| 14, 15, 16, 41, 65, 66, 91                                                            | V <sub>DD</sub>  | Supply                  | <b>Power Supply for Core</b>                                                                                                                                                                                                                                                                                                                                            |
| 4, 11, 20, 27, 54, 61, 70, 77                                                         | V <sub>DDQ</sub> | Supply                  | <b>Power Supply for Output Buffers</b>                                                                                                                                                                                                                                                                                                                                  |
| 17, 40, 67, 90                                                                        | V <sub>SS</sub>  | Ground                  | <b>Ground for Core</b>                                                                                                                                                                                                                                                                                                                                                  |
| 5, 10, 21, 26, 55, 60, 71, 76                                                         | V <sub>SSQ</sub> | Ground                  | <b>Ground for Output Buffers</b>                                                                                                                                                                                                                                                                                                                                        |

**OPERATING MODE****(1) Synchronous Input Truth Table**

| OPERATION                     | $\overline{WE}$ | ADV | CE       | $\overline{BW}$ | Addr. Used | $\overline{CKE}$ | ZZ | I/O<br>(2 cycles later) |
|-------------------------------|-----------------|-----|----------|-----------------|------------|------------------|----|-------------------------|
| Read (begin burst)            | H               | L   | Select   | x               | External   | L                | L  | Output                  |
| Read (continue burst)         | x               | H   | x        | x               | Internal   | L                | L  | Output                  |
| Write (begin burst)           | L               | L   | Select   | L               | External   | L                | L  | Input                   |
| Write (continue burst)        | x               | H   | x        | L               | Internal   | L                | L  | Input                   |
| NOP/Write Abort (begin burst) | L               | L   | Select   | H               | x          | L                | L  | Hi-Z                    |
| Write Abort (continue burst)  | x               | H   | x        | H               | Internal   | L                | L  | Hi-Z                    |
| Deselected                    | x               | L   | Deselect | x               | x          | L                | L  | Hi-Z                    |
| Deselect Continue (Note 2)    | x               | H   | x        | x               | x          | L                | L  | Hi-Z                    |
| Ignore Clock Edge (Note 3)    | x               | x   | x        | x               | x          | H                | L  | Previous value          |
| Snooze                        | x               | x   | x        | x               | x          | x                | H  | Hi-Z                    |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

2. A Deselect Continue cycle can only be entered if a Deselect cycle is executed before it.

3. When the Ignore Clock Edge command is asserted during a Read operation, the output data for the previous cycle still appear on the I/O pins. When the command is asserted during a Write operation, the I/O pins remain at Hi-Z and the Write operation is not executed.

4. All synchronous Inputs must exhibit adequate setup and hold times either side of the rising edge of the CLK pin.

5. ZZ input is asynchronous, but is included in this table.

**(2) Write Enable Truth Table**

| OPERATION | $\overline{WE}$ | $\overline{BW1}$ | $\overline{BW2}$ | I/O1 to I/O9 | I/O10 to I/O18 |
|-----------|-----------------|------------------|------------------|--------------|----------------|
| Read      | H               | x                | x                | Output       | Output         |
| Write     | L               | L                | L                | Input        | Input          |
|           | L               | L                | H                | Input        | Hi-Z           |
|           | L               | H                | L                | Hi-Z         | Input          |
|           | L               | H                | H                | Hi-Z         | Hi-Z           |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

2. The status for I/O pins described in this column appears two clock cycles after the cycle in which the Read or Write command is asserted.

**(3) Asynchronous Inputs Truth Table**

| OPERATION           | $\overline{OE}$ | ZZ | I/O       |
|---------------------|-----------------|----|-----------|
| Read                | L               | L  | Dout      |
|                     | H               | L  | Hi-Z      |
| Write               | x               | L  | Din, Hi-Z |
| Stop clock (Note 2) | H               | L  | Hi-Z      |
|                     | L               | L  | Low-Z     |
| Snooze (Note 3)     | x               | H  | Hi-Z      |

Notes: 1. H means logical High and L means logical Low. X means Don't care.

2. The Stop CLK Mode achieves Low-Power Standby by stopping the input clock.

3. The Snooze Mode achieves Low-Power Standby by asserting the ZZ pin.

4. The cycle immediately prior to a snooze brought about by the ZZ pin must be a Read Mode or Deselect Mode cycle.

5. Memory data is retained during Snooze Mode cycles.

**(4) Burst Sequence**

| MODE PIN | BURST OPERATION         |
|----------|-------------------------|
| L        | Linear burst order      |
| H or NC  | Interleaved burst order |

a) Linear Burst Sequence (MODE input =  $V_{SS}$ )Bit Order:  $A_{18}, \dots, A_1, A_0$ 

| 1st Address<br>(external) | 2nd Address<br>(internal) | 3rd Address<br>(internal) | 4th Address<br>(internal) |
|---------------------------|---------------------------|---------------------------|---------------------------|
| XX ..... XX00             | XX ..... XX01             | XX ..... XX10             | XX ..... XX11             |
| XX ..... XX01             | XX ..... XX10             | XX ..... XX11             | XX ..... XX00             |
| XX ..... XX10             | XX ..... XX11             | XX ..... XX00             | XX ..... XX01             |
| XX ..... XX11             | XX ..... XX00             | XX ..... XX01             | XX ..... XX10             |

b) Interleaved Burst Sequence (MODE input =  $V_{DD}$  or NC)Bit Order:  $A_{18}, \dots, A_1, A_0$ 

| 1st Address<br>(external) | 2nd Address<br>(internal) | 3rd Address<br>(internal) | 4th Address<br>(internal) |
|---------------------------|---------------------------|---------------------------|---------------------------|
| XX ..... XX00             | XX ..... XX01             | XX ..... XX10             | XX ..... XX11             |
| XX ..... XX01             | XX ..... XX00             | XX ..... XX11             | XX ..... XX10             |
| XX ..... XX10             | XX ..... XX11             | XX ..... XX00             | XX ..... XX01             |
| XX ..... XX11             | XX ..... XX10             | XX ..... XX01             | XX ..... XX00             |

**DEVICE OPERATION**

## (1) Read Operation

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|-------------------------|
| n     | A0      | H               | x               | L   | L               | x               | L                | x   | Address & control valid |
| n + 1 | x       | x               | x               | x   | x               | x               | L                | x   |                         |
| n + 2 | x       | x               | x               | x   | x               | L               | x                | Q0  | Read out A0             |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

## (2) Burst Read Operation

| CYCLE  | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O    | OPERATION               |
|--------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|--------|-------------------------|
| n      | A0      | H               | x               | L   | L               | x               | L                | x      | Address & control valid |
| n + 1  | x       | x               | x               | H   | x               | x               | L                | x      |                         |
| n + 2  | x       | x               | x               | H   | x               | L               | L                | Q0     | Read out A0             |
| n + 3  | x       | x               | x               | H   | x               | L               | L                | Q0 + 1 | Read out A0 + 1         |
| n + 4  | x       | x               | x               | H   | x               | L               | L                | Q0 + 2 | Read out A0 + 2         |
| n + 5  | A1      | H               | x               | L   | L               | L               | L                | Q0 + 3 | Read out A0 + 3         |
| n + 6  | x       | x               | x               | H   | x               | L               | L                | Q0     | Read out A0             |
| n + 7  | x       | x               | x               | H   | x               | L               | L                | Q1     | Read out A1             |
| n + 8  | A2      | H               | x               | L   | L               | L               | L                | Q1 + 1 | Read out A1 + 1         |
| n + 9  | A3      | H               | x               | L   | L               | L               | L                | Q1 + 2 | Read out A1 + 2         |
| n + 10 | x       | x               | x               | x   | x               | L               | L                | Q2     | Read out A2             |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

## (3) Write Operation

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|-------------------------|
| n     | A0      | L               | L               | L   | L               | x               | L                | x   | Address & control valid |
| n+1   | x       | x               | x               | x   | x               | x               | L                | x   |                         |
| n+2   | x       | x               | x               | x   | x               | x               | L                | D0  | Write to A0             |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

## (4) Burst Write Operation

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O  | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|------|-------------------------|
| n     | A0      | L               | L               | L   | L               | x               | L                | x    | Address & control valid |
| n+1   | x       | x               | L               | H   | x               | x               | L                | x    |                         |
| n+2   | x       | x               | L               | H   | x               | x               | L                | D0   | Write A0                |
| n+3   | x       | x               | L               | H   | x               | x               | L                | D0+1 | Write A0+1              |
| n+4   | x       | x               | L               | H   | x               | x               | L                | D0+2 | Write A0+2              |
| n+5   | A1      | L               | L               | L   | L               | x               | L                | D0+3 | Write A0+3              |
| n+6   | x       | x               | L               | H   | x               | x               | L                | D0   | Write A0                |
| n+7   | x       | x               | L               | H   | x               | x               | L                | D1   | Write A1                |
| n+8   | A2      | L               | L               | L   | L               | x               | L                | D1+1 | Write A1+1              |
| n+9   | A3      | L               | L               | L   | L               | x               | L                | D1+2 | Write A1+2              |
| n+10  | x       | x               | L               | x   | x               | x               | L                | D2   | Write A2                |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

## (5) Read Operation with Clock Enable

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION                  |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|----------------------------|
| n     | A0      | H               | x               | L   | L               | x               | L                | x   | Address & control valid    |
| n+1   | x       | x               | x               | x   | x               | x               | H                | x   | Ignore cycle               |
| n+2   | A1      | H               | x               | L   | L               | x               | L                | x   | Address & control valid    |
| n+3   | x       | x               | x               | x   | x               | L               | H                | Q0  | Ignore clock, Q0 is on bus |
| n+4   | x       | x               | x               | x   | x               | L               | H                | Q0  | Ignore clock, Q0 is on bus |
| n+5   | A2      | H               | x               | L   | L               | L               | L                | Q0  | Read out A0                |
| n+6   | A3      | H               | x               | L   | L               | L               | L                | Q1  | Read out A1                |
| n+7   | x       | x               | x               | x   | x               | L               | L                | Q2  | Read out A2                |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.

## (6) Write Operation with Clock Enable

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|-------------------------|
| n     | A0      | L               | L               | L   | L               | x               | L                | x   | Address & control valid |
| n+1   | x       | x               | x               | x   | x               | x               | H                | x   | Ignore clock            |
| n+2   | A1      | L               | L               | L   | L               | x               | L                | x   | Address & control valid |
| n+3   | x       | x               | x               | x   | x               | x               | H                | x   | Ignore clock            |
| n+4   | x       | x               | x               | x   | x               | x               | H                | x   | Ignore clock            |
| n+5   | A2      | L               | L               | L   | L               | x               | L                | D0  | Address & control valid |
| n+6   | A3      | L               | L               | L   | L               | x               | L                | D1  | Write A1                |
| n+7   | x       | x               | x               | x   | x               | x               | L                | D2  | Write A2                |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.

## (7) Read Operation with Chip Enable

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|-------------------------|
| n     | A0      | H               | x               | L   | L               | x               | L                | x   | Address & control valid |
| n+1   | x       | x               | x               | L   | H               | x               | L                | x   | Deselect                |
| n+2   | A1      | H               | x               | L   | L               | L               | L                | Q0  | Read A0                 |
| n+3   | x       | x               | x               | L   | H               | x               | L                | Z   | Deselect                |
| n+4   | x       | x               | x               | L   | H               | L               | L                | Q1  | Read A1                 |
| n+5   | A2      | H               | x               | L   | L               | x               | L                | Z   | Deselect                |
| n+6   | x       | x               | x               | L   | H               | x               | L                | Z   | Deselect                |
| n+7   | x       | x               | x               | L   | H               | L               | L                | Q2  | Read A2                 |

Note 1: H means logical High and L means logical Low. X means Don't care. Q is data output.  
Z means Hi-Z.

## (8) Write Operation with Chip Enable

| CYCLE | ADDRESS | $\overline{WE}$ | $\overline{BW}$ | ADV | $\overline{CE}$ | $\overline{OE}$ | $\overline{CKE}$ | I/O | OPERATION               |
|-------|---------|-----------------|-----------------|-----|-----------------|-----------------|------------------|-----|-------------------------|
| n     | A0      | L               | L               | L   | L               | x               | L                | x   | Address & control valid |
| n+1   | x       | x               | x               | L   | H               | x               | L                | x   | Deselect                |
| n+2   | A1      | L               | L               | L   | L               | x               | L                | D0  | Write A0                |
| n+3   | x       | x               | x               | L   | H               | x               | L                | Z   | Deselect                |
| n+4   | x       | x               | x               | L   | H               | x               | L                | D1  | Write A1                |
| n+5   | A2      | L               | L               | L   | L               | x               | L                | Z   | Deselect                |
| n+6   | x       | x               | x               | L   | H               | x               | L                | Z   | Deselect                |
| n+7   | x       | x               | x               | L   | H               | x               | L                | D2  | Write A2                |

Note 1: H means logical High and L means logical Low. X means Don't care. D is data input.  
Z means Hi-Z.

ABSOLUTE MAXIMUM RATINGS

| SYMBOL              | RATING                             | VALUE                                             | UNIT |
|---------------------|------------------------------------|---------------------------------------------------|------|
| V <sub>DD</sub>     | Power Supply Voltage               | − 0.5 to 4.6                                      | V    |
| V <sub>DDQ</sub>    | Output Buffer Power Supply Voltage | − 0.5 to V <sub>DD</sub> + 0.5 (≦ 4.6 V max)      | V    |
| V <sub>IN</sub>     | Input Terminal Voltage             | − 0.5 * to 4.6                                    | V    |
| V <sub>I/O</sub>    | Input/Output Terminal Voltage      | − 0.5 * to V <sub>DDQ</sub> + 0.5** (≦ 4.6 V max) | V    |
| P <sub>D</sub>      | Power Dissipation                  | 1.5                                               | W    |
| T <sub>solder</sub> | Soldering Temperature (10s)        | 260                                               | °C   |
| T <sub>strg</sub>   | Storage Temperature                | − 65 to 150                                       | °C   |
| T <sub>opr</sub>    | Operating Temperature              | − 10 to 85                                        | °C   |

\*: −1.0 V with a pulse width of 20% of t<sub>KC(min)</sub> (3 ns max)  
\*\*: V<sub>DDQ</sub> + 1.0 V with a pulse width of 20% of t<sub>KC(min)</sub> (3 ns max)

RECOMMENDED DC OPERATING CONDITIONS (Ta = 0 to 70°C)

| SYMBOL           | PARAMETER                              | MIN                   | TYP.            | MAX                     | UNIT |
|------------------|----------------------------------------|-----------------------|-----------------|-------------------------|------|
| V <sub>DD</sub>  | Power Supply Voltage                   | 3.135                 | 3.3             | 3.465                   | V    |
| V <sub>DDQ</sub> | Output Buffer Power Supply Voltage     | 3.135                 | 3.3             | 3.465                   | V    |
| V <sub>IH</sub>  | Input High Voltage                     | 2.0                   | −               | V <sub>DD</sub> + 0.3** | V    |
| V <sub>IH1</sub> | Input High Voltage for MODE pin        | V <sub>DD</sub> − 0.3 | V <sub>DD</sub> | V <sub>DD</sub> + 0.3   | V    |
| V <sub>IL</sub>  | Input Low Voltage                      | − 0.3 *               | −               | 0.8                     | V    |
| V <sub>IL1</sub> | Input Low Voltage for MODE and NU pins | − 0.3                 | 0.0             | 0.3                     | V    |

\*: −0.7 V with a pulse width of 20% of t<sub>KC(min)</sub> (3 ns max)  
\*\*: V<sub>DDQ</sub> + 0.7 V with a pulse width of 20% of t<sub>KC(min)</sub> (3 ns max)

Note: NU pin must be low or not connected.

DC CHARACTERISTICS ( $T_a = 0$  to  $70^\circ\text{C}$ ,  $V_{DD} = V_{DDQ} = 3.3\text{ V} \pm 5\%$ )

| SYMBOL     | PARAMETER                                       | TEST CONDITIONS                                                                                                                     | MIN             | TYP. | MAX | UNIT          |
|------------|-------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-----------------|------|-----|---------------|
| $I_{IL}$   | Input Leakage Current                           | $V_{IN} = 0$ to $V_{DD}$                                                                                                            | -1              | -    | 1   | $\mu\text{A}$ |
| $I_{NU}$   | Input Current (NU pin)                          | $V_{IN} = 0\text{ V}$ to $0.3\text{ V}$                                                                                             | -1              | -    | 1   | $\mu\text{A}$ |
| $I_{LO}$   | Output Leakage Current                          | Device Deselected or Output Deselected,<br>$V_{OUT} = 0$ to $V_{DDQ}$                                                               | -1              | -    | 1   | $\mu\text{A}$ |
| $V_{OH}$   | Output High Voltage                             | $I_{OH} = -8\text{ mA}$                                                                                                             | 2.4             | -    | -   | V             |
|            |                                                 | $I_{OH} = -100\text{ }\mu\text{A}$                                                                                                  | $V_{DDQ} - 0.2$ | -    | -   |               |
| $V_{OL}$   | Output Low Voltage                              | $I_{OL} = 8\text{ mA}$                                                                                                              | -               | -    | 0.4 |               |
|            |                                                 | $I_{OL} = 100\text{ }\mu\text{A}$                                                                                                   | -               | -    | 0.2 |               |
| $I_{DDO1}$ | Operating Current                               | $I_{OUT} = 0\text{ mA}$ , all inputs = $V_{DD} - 0.2\text{ V}/0.2\text{ V}$<br>Clock $\geq t_{KC}(\text{min})$                      | 150MHz          | -    | -   | mA            |
|            |                                                 |                                                                                                                                     | 143MHz          | -    | -   |               |
|            |                                                 |                                                                                                                                     | 133MHz          | -    | -   |               |
| $I_{DDO2}$ | Operating Current (idle)                        | Device Deselected<br>$I_{OUT} = 0\text{ mA}$ , all inputs = $V_{DD} - 0.2\text{ V}/0.2\text{ V}$<br>Clock $\geq t_{KC}(\text{min})$ | 150MHz          | -    | -   | mA            |
|            |                                                 |                                                                                                                                     | 143MHz          | -    | -   |               |
|            |                                                 |                                                                                                                                     | 133MHz          | -    | -   |               |
| $I_{DDS1}$ | Standby Current (TTL level)                     | Clock = $V_{SS}$ , all inputs = $V_{IH}$ or $V_{IL}$                                                                                | -               | -    | 60  | mA            |
| $I_{DDS2}$ | Standby Current (MOS level)                     | Clock = $V_{SS}$ , all inputs = $V_{DD} - 0.2\text{ V}$ or $0.2\text{ V}$                                                           | -               | -    | 10  | mA            |
| $I_{DDS3}$ | Standby Current (Snooze Mode)                   | $ZZ \geq V_{DD} - 0.2\text{ V}$<br>all inputs = $V_{DD} - 0.2\text{ V}$ or $0.2\text{ V}$<br>Clock $\geq t_{KC}(\text{min})$        | -               | -    | 10  | mA            |
| $I_{DDS4}$ | Standby Current ( $\overline{\text{CKE}}$ Mode) | $\overline{\text{CKE}} \geq V_{IH}$<br>All inputs = $V_{DD} - 0.2\text{ V}$ or $0.2\text{ V}$<br>Clock $\geq t_{KC}(\text{min})$    | -               | -    | 10  | mA            |

Note: Operating Current( $I_{DDO1}$ ) is specified with 50% Read cycles and 50% Write cycles.

CAPACITANCE ( $T_a = 25^\circ\text{C}$ ,  $f = 1.0\text{ MHz}$ )

| SYMBOL    | PARAMETER                | TEST CONDITIONS        | MAX | UNIT |
|-----------|--------------------------|------------------------|-----|------|
| $C_{IN}$  | Input Capacitance        | $V_{IN} = \text{GND}$  | 5   | pF   |
| $C_{I/O}$ | Input/Output Capacitance | $V_{I/O} = \text{GND}$ | 7   | pF   |
| $C_{NU}$  | Input Capacitance of NU  | $V_{IN} = \text{GND}$  | 10  | pF   |

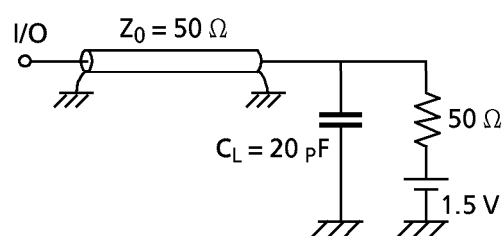
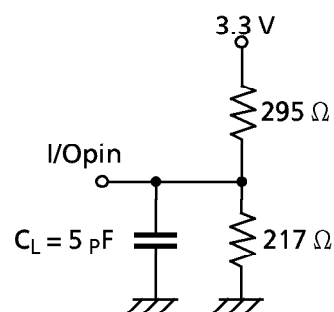
Note: This parameter is sampled periodically and is not tested for every device.

**AC CHARACTERISTICS** ( $T_a = 0$  to  $70^\circ\text{C}$ ,  $V_{DD} = V_{DDQ} = 3.3\text{ V} \pm 5\%$ )

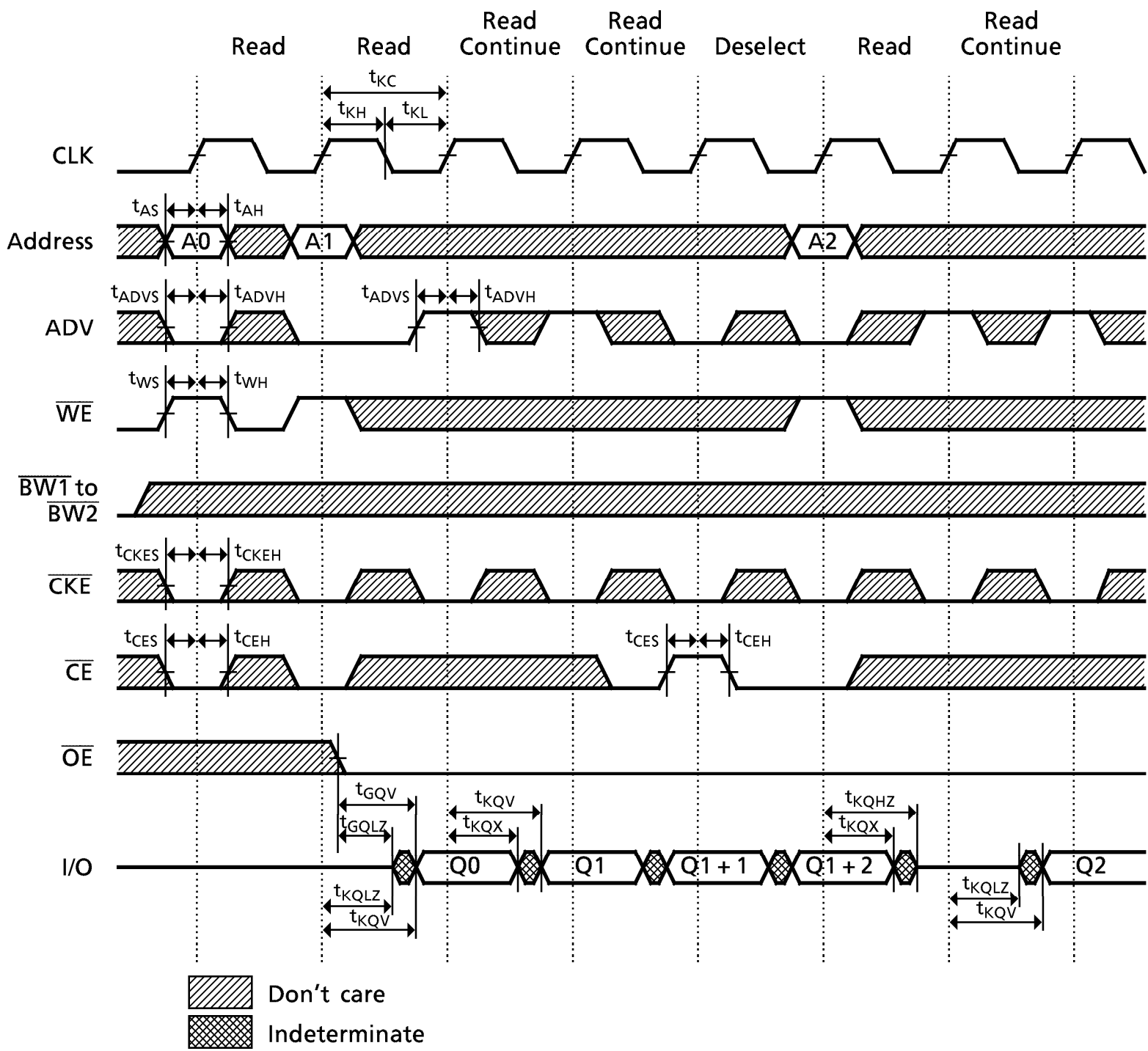
| SYMBOL     | PARAMETER                             | TC55VD818FF-150 |           | TC55VD818FF-143 |           | TC55VD818FF-133 |           | UNIT |
|------------|---------------------------------------|-----------------|-----------|-----------------|-----------|-----------------|-----------|------|
|            |                                       | MIN             | MAX       | MIN             | MAX       | MIN             | MAX       |      |
| $t_{KC}$   | CLK Cycle Time                        | 6.6             | –         | 7.0             | –         | 7.5             | –         | ns   |
| $t_{KH}$   | CLK High Pulse Width                  | 2               | –         | 2               | –         | 2.3             | –         |      |
| $t_{KL}$   | CLK Low Pulse Width                   | 2               | –         | 2               | –         | 2.3             | –         |      |
| $t_{KQV}$  | CLK High to Output Valid              | –               | 3.8       | –               | 4         | –               | 4.2       |      |
| $t_{KQX}$  | CLK High to Output Invalid            | 1.5             | –         | 1.5             | –         | 1.5             | –         |      |
| $t_{KQLZ}$ | CLK High to Output Low-Z              | 2.0             | –         | 2.0             | –         | 2.0             | –         |      |
| $t_{KQHZ}$ | CLK High to Output High-Z             | 1.5             | 3.5       | 1.5             | 3.5       | 1.5             | 3.5       |      |
| $t_{GQV}$  | $\overline{OE}$ Low to Output Valid   | –               | 4         | –               | 4         | –               | 4.2       |      |
| $t_{GQLZ}$ | $\overline{OE}$ Low to Output Low-Z   | 1.5             | –         | 1.5             | –         | 1.5             | –         |      |
| $t_{GQHZ}$ | $\overline{OE}$ High to Output High-Z | 1.5             | 4         | 1.5             | 4         | 1.5             | 4.2       |      |
| $t_{AS}$   | Address Setup Time from CLK           | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{DS}$   | Data Setup Time from CLK              | 1.5             | –         | 1.5             | –         | 1.7             | –         |      |
| $t_{WS}$   | $\overline{WE}$ Setup Time from CLK   | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{CES}$  | CE Setup Time from CLK                | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{ADVS}$ | ADV Setup Time from CLK               | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{BWS}$  | $\overline{BW}$ Setup Time from CLK   | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{CKES}$ | $\overline{CKE}$ Setup Time from CLK  | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{AH}$   | Address Hold Time from CLK            | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{DH}$   | Data Hold Time from CLK               | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{WH}$   | $\overline{WE}$ Hold Time from CLK    | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{CEH}$  | CE Hold Time from CLK                 | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{ADVH}$ | ADV Hold Time from CLK                | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{BWH}$  | $\overline{BW}$ Hold Time from CLK    | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{CKEH}$ | $\overline{CKE}$ Hold Time from CLK   | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{ZZ}$   | ZZ High to Input Ignored              | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZR}$  | ZZ Low to Input Sampled               | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZHZ}$ | ZZ High to Output High-Z              | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZLZ}$ | ZZ Low to Output Low-Z                | 0               | –         | 0               | –         | 0               | –         |      |

**AC TEST CONDITIONS**

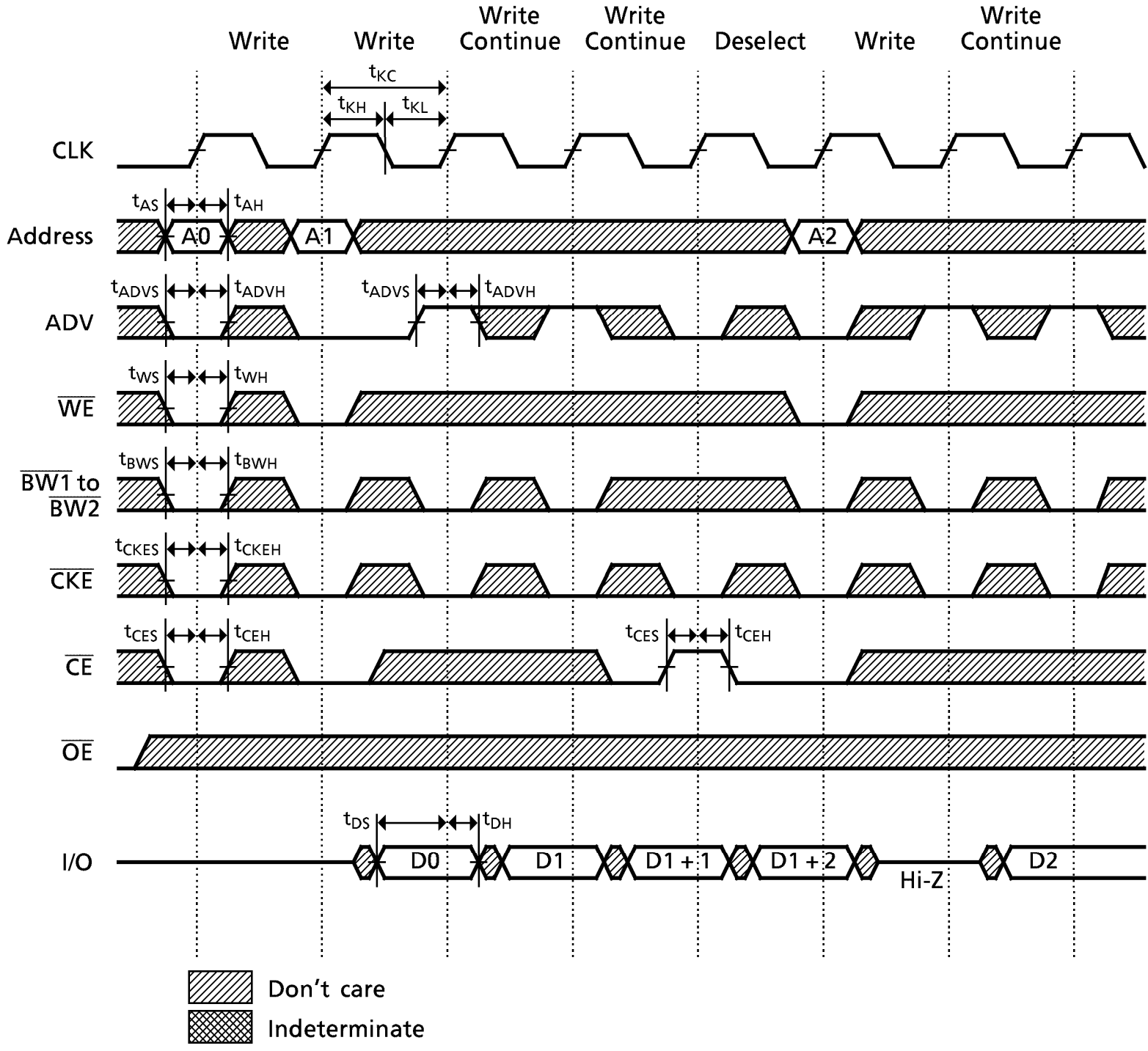
|                                           |                               |
|-------------------------------------------|-------------------------------|
| Input Pulse Level                         | 3.0 V/0.0 V                   |
| Input Pulse Rise and Fall Time            | 1 V/ns(20%/80%)               |
| Input Timing Measurement Reference Level  | 1.5 V                         |
| Output Timing Measurement Reference Level | 1.5 V                         |
| Output Load                               | As shown in Fig. 1 and Fig. 2 |

**Fig. 1 : AC test load****Fig. 2 : AC test load (for Enable/Disable spec)**

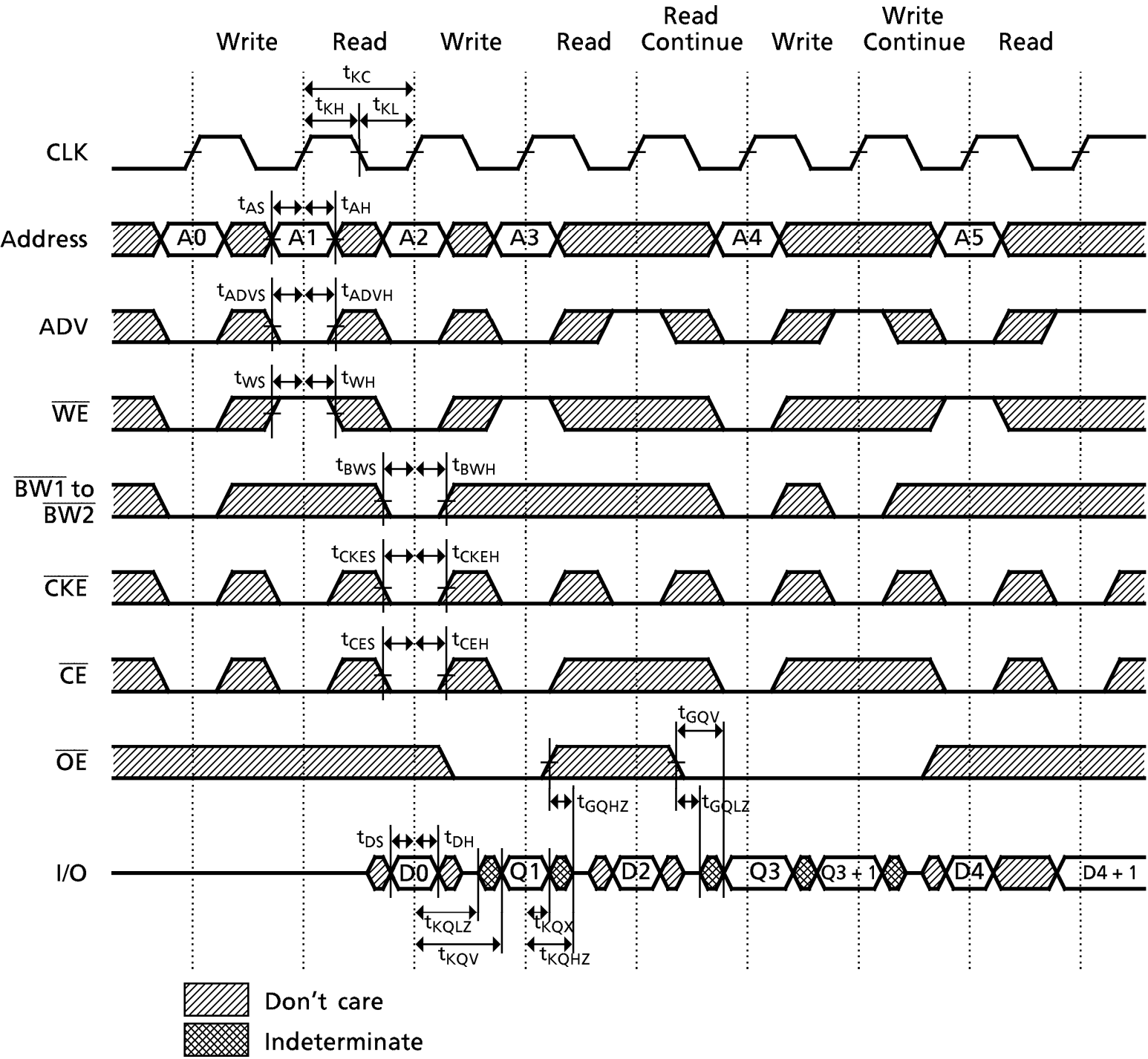
TIMING DIAGRAMS  
READ CYCLE



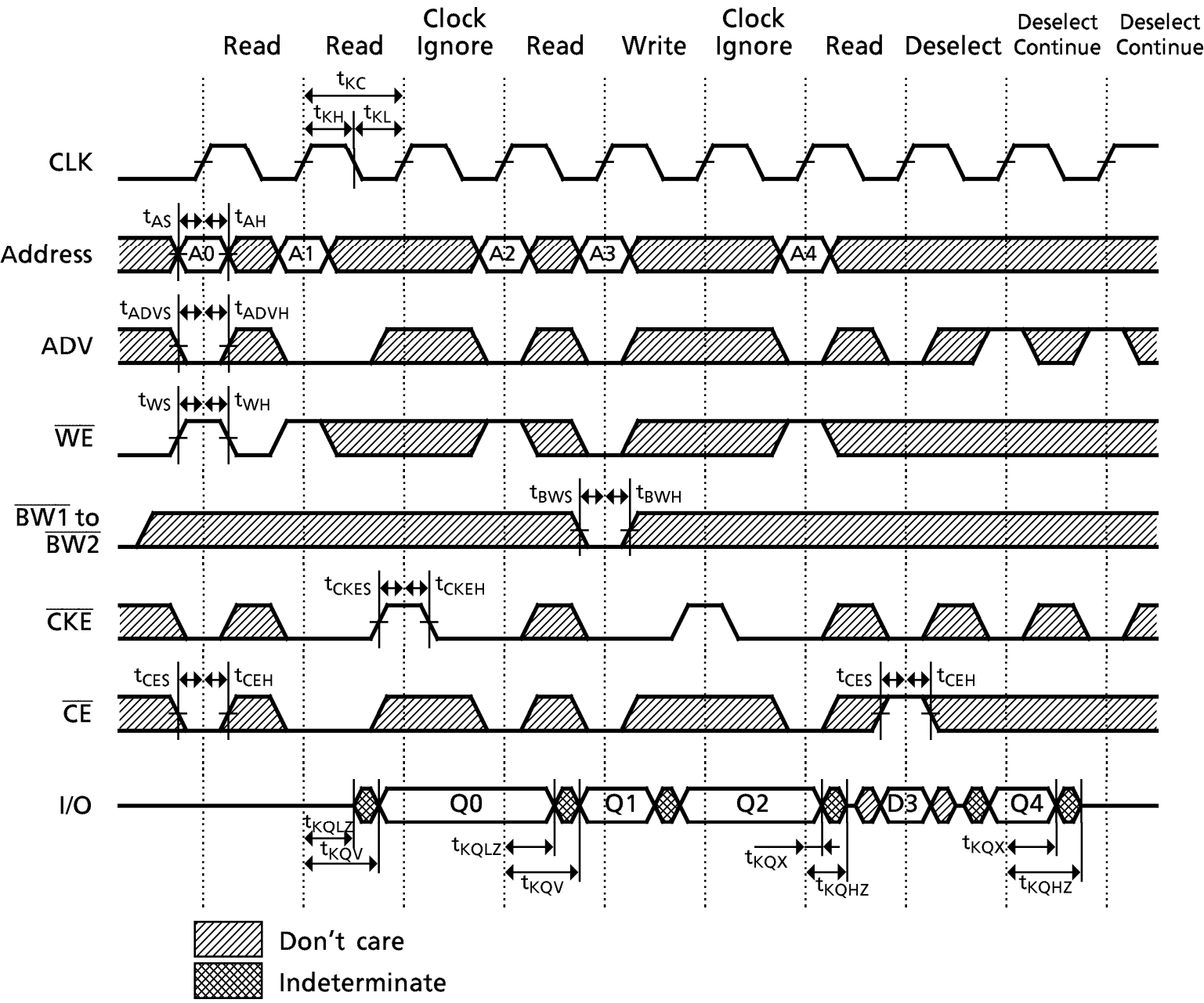
WRITE CYCLE



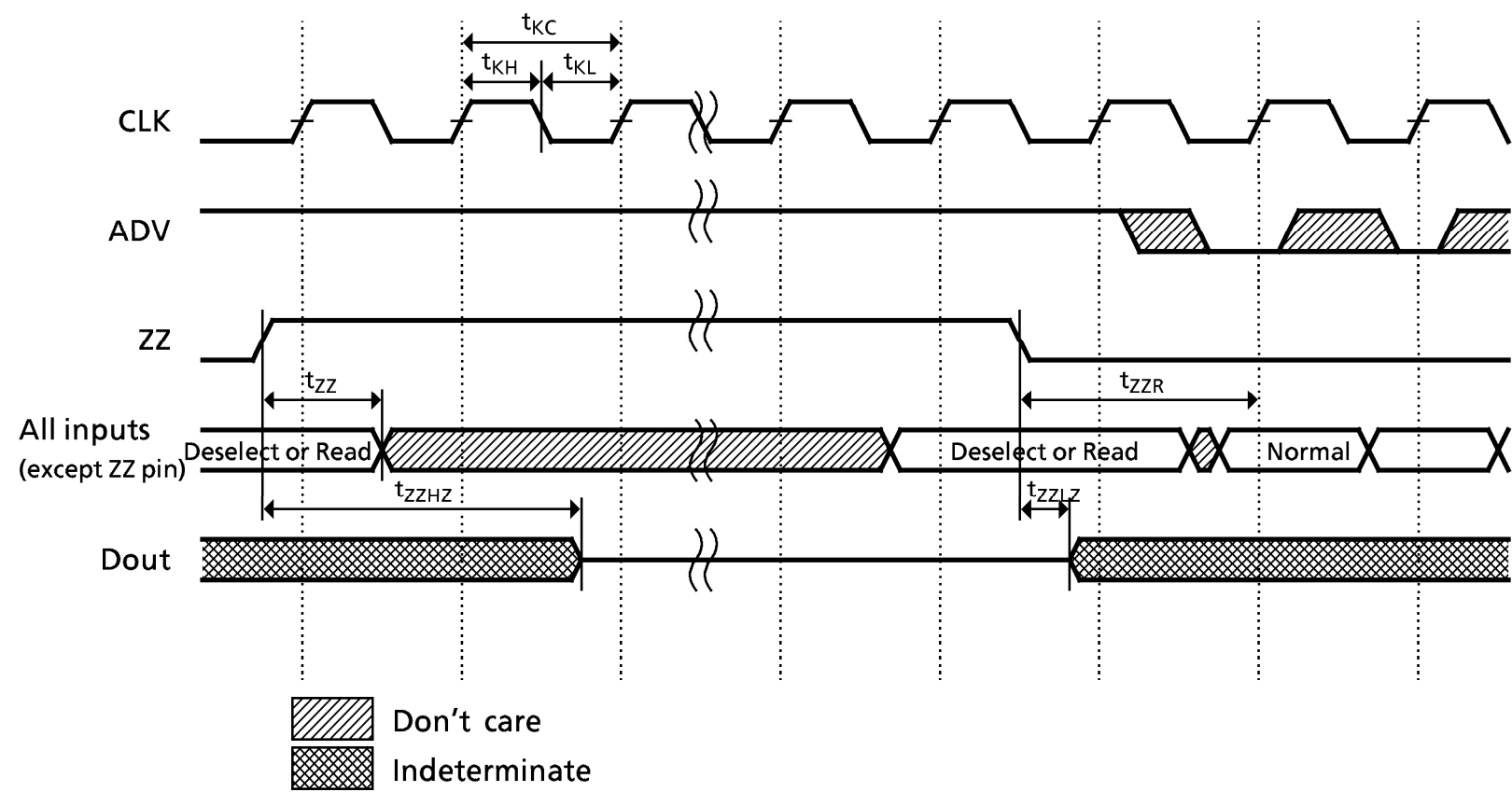
WRITE/READ CYCLE



CLOCK IGNORE/DESELECT CYCLE



SNOOZE CYCLE



- Notes: 1. The 2 cycles immediately prior to a Snooze brought about by the ZZ pin must be Read or Deselect cycles.
2. Memory data is retained during Snooze cycles.

## ■ $V_{DDQ} = 2.5V$ Interface specification

### RECOMMENDED DC OPERATING CONDITIONS ( $T_a = 0$ to $70^\circ C$ )

| SYMBOL    | PARAMETER                                       | MIN            | TYP.     | MAX                   | UNIT |
|-----------|-------------------------------------------------|----------------|----------|-----------------------|------|
| $V_{DD}$  | Power Supply Voltage                            | 3.135          | 3.3      | 3.465                 | V    |
| $V_{DDQ}$ | Output Buffer Power Supply Voltage              | 2.375          | 2.5      | 2.9                   | V    |
| $V_{IH}$  | Input High Voltage for Address and Control pins | 1.7            | –        | $V_{DD} + 0.3^{**}$   | V    |
|           | Input High Voltage for I/O pins                 | 1.7            | –        | $V_{DDQ} + 0.3^{***}$ |      |
| $V_{IH1}$ | Input High Voltage for MODE pin                 | $V_{DD} - 0.3$ | $V_{DD}$ | $V_{DD} + 0.3$        | V    |
| $V_{IL}$  | Input Low Voltage                               | $-0.3^*$       | –        | 0.7                   | V    |
| $V_{IL1}$ | Input Low Voltage for MODE and NU pins          | $-0.3$         | 0.0      | 0.3                   | V    |

\*:  $-0.7V$  with a pulse width of 20% of  $t_{KC}(\min)$  (3 ns max)

\*\*:  $V_{DD} + 0.7V$  with a pulse width of 20% of  $t_{KC}(\min)$  (3 ns max)

\*\*\*:  $V_{DDQ} + 0.7V$  with a pulse width of 20% of  $t_{KC}(\min)$  (3 ns max)

NOTE: NU pin must be low or not connected.

### DC CHARACTERISTICS ( $T_a = 0$ to $70^\circ C$ , $V_{DD} = 3.3V \pm 5\%$ , $V_{DDQ} = 2.375V$ to $2.9V$ )

| SYMBOL     | PARAMETER                     | TEST CONDITIONS                                                                                       |        | MIN             | TYP. | MAX | UNIT    |
|------------|-------------------------------|-------------------------------------------------------------------------------------------------------|--------|-----------------|------|-----|---------|
| $I_{IL}$   | Input Leakage Current         | $V_{IN} = 0$ to $V_{DD}$                                                                              |        | – 1             | –    | 1   | $\mu A$ |
| $I_{NU}$   | Input Current (NU pin)        | $V_{IN} = 0V$ to $0.3V$                                                                               |        | – 1             | –    | 1   | $\mu A$ |
| $I_{LO}$   | Output Leakage Current        | Device Deselected or Output Deselected, $V_{OUT} = 0$ to $V_{DDQ}$                                    |        | – 1             | –    | 1   | $\mu A$ |
| $V_{OH}$   | Output High Voltage           | $I_{OH} = -2mA$                                                                                       |        | 1.7             | –    | –   | V       |
|            |                               | $I_{OH} = -100\mu A$                                                                                  |        | $V_{DDQ} - 0.2$ | –    | –   |         |
| $V_{OL}$   | Output Low Voltage            | $I_{OL} = 2mA$                                                                                        |        | –               | –    | 0.7 |         |
|            |                               | $I_{OL} = 100\mu A$                                                                                   |        | –               | –    | 0.2 |         |
| $I_{DDO1}$ | Operating Current             | $I_{OUT} = 0mA$ , all inputs = $V_{DD} - 0.2V/0.2V$<br>Clock $\geq t_{KC}(\min)$                      | 150MHz | –               | –    | 420 | mA      |
|            |                               |                                                                                                       | 143MHz | –               | –    | 400 |         |
|            |                               |                                                                                                       | 133MHz | –               | –    | 380 |         |
| $I_{DDO2}$ | Operating Current (idle)      | Device Deselected<br>$I_{OUT} = 0mA$ , all inputs = $V_{DD} - 0.2V/0.2V$<br>Clock $\geq t_{KC}(\min)$ | 150MHz | –               | –    | 180 | mA      |
|            |                               |                                                                                                       | 143MHz | –               | –    | 170 |         |
|            |                               |                                                                                                       | 133MHz | –               | –    | 160 |         |
| $I_{DDS2}$ | Standby Current (MOS level)   | Clock = $V_{SS}$ , all inputs = $V_{DD} - 0.2V$ or $0.2V$                                             |        | –               | –    | 10  | mA      |
| $I_{DDS3}$ | Standby Current (Snooze Mode) | $ZZ \geq V_{DD} - 0.2V$<br>all inputs = $V_{DD} - 0.2V$ or $0.2V$<br>Clock $\geq t_{KC}(\min)$        |        | –               | –    | 10  | mA      |
| $I_{DDS4}$ | Standby Current (CKE Mode)    | $\overline{CKE} \geq V_{IH}$<br>All inputs = $V_{DD} - 0.2V$ or $0.2V$<br>Clock $\geq t_{KC}(\min)$   |        | –               | –    | 10  | mA      |

Note: Operating Current( $I_{DDO1}$ ) is specified with 50% Read cycles and 50% Write cycles.

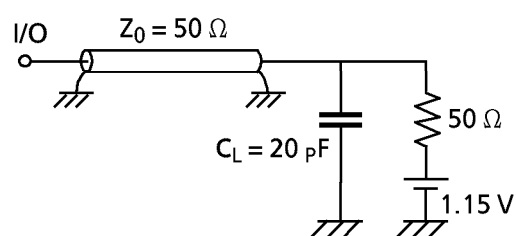
**AC CHARACTERISTICS** ( $T_a = 0$  to  $70^\circ\text{C}$ ,  $V_{DD} = 3.3\text{ V} \pm 5\%$ ,  $V_{DDQ} = 2.375\text{ V}$  to  $2.9\text{ V}$ )

| SYMBOL     | PARAMETER                             | TC55VD818FF-150 |           | TC55VD818FF-143 |           | TC55VD818FF-133 |           | UNIT |
|------------|---------------------------------------|-----------------|-----------|-----------------|-----------|-----------------|-----------|------|
|            |                                       | MIN             | MAX       | MIN             | MAX       | MIN             | MAX       |      |
| $t_{KC}$   | CLK Cycle Time                        | 6.6             | –         | 7.0             | –         | 7.5             | –         | ns   |
| $t_{KH}$   | CLK High Pulse Width                  | 2               | –         | 2               | –         | 2.3             | –         |      |
| $t_{KL}$   | CLK Low Pulse Width                   | 2               | –         | 2               | –         | 2.3             | –         |      |
| $t_{KQV}$  | CLK High to Output Valid              | –               | 3.8       | –               | 4         | –               | 4.2       |      |
| $t_{KQX}$  | CLK High to Output Invalid            | 1.5             | –         | 1.5             | –         | 1.5             | –         |      |
| $t_{KQLZ}$ | CLK High to Output Low-Z              | 2.0             | –         | 2.0             | –         | 2.0             | –         |      |
| $t_{KQHZ}$ | CLK High to Output High-Z             | 1.5             | 3.5       | 1.5             | 3.5       | 1.5             | 3.5       |      |
| $t_{GQV}$  | $\overline{OE}$ Low to Output Valid   | –               | 4         | –               | 4         | –               | 4.2       |      |
| $t_{GQLZ}$ | $\overline{OE}$ Low to Output Low-Z   | 1.5             | –         | 1.5             | –         | 1.5             | –         |      |
| $t_{GQHZ}$ | $\overline{OE}$ High to Output High-Z | 1.5             | 4         | 1.5             | 4         | 1.5             | 4.2       |      |
| $t_{AS}$   | Address Setup Time from CLK           | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{DS}$   | Data Setup Time from CLK              | 1.5             | –         | 1.5             | –         | 1.7             | –         |      |
| $t_{WS}$   | $\overline{WE}$ Setup Time from CLK   | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{CES}$  | CE Setup Time from CLK                | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{ADVS}$ | ADV Setup Time from CLK               | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{BWS}$  | $\overline{BW}$ Setup Time from CLK   | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{CKES}$ | $\overline{CKE}$ Setup Time from CLK  | 2               | –         | 2               | –         | 2               | –         |      |
| $t_{AH}$   | Address Hold Time from CLK            | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{DH}$   | Data Hold Time from CLK               | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{WH}$   | $\overline{WE}$ Hold Time from CLK    | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{CEH}$  | CE Hold Time from CLK                 | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{ADVH}$ | ADV Hold Time from CLK                | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{BWH}$  | $\overline{BW}$ Hold Time from CLK    | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{CKEH}$ | $\overline{CKE}$ Hold Time from CLK   | 0.5             | –         | 0.5             | –         | 0.5             | –         |      |
| $t_{ZZ}$   | ZZ High to Input Ignored              | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZR}$  | ZZ Low to Input Sampled               | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZHZ}$ | ZZ High to Output High-Z              | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ | 0               | $2t_{KC}$ |      |
| $t_{ZZLZ}$ | ZZ Low to Output Low-Z                | 0               | –         | 0               | –         | 0               | –         |      |

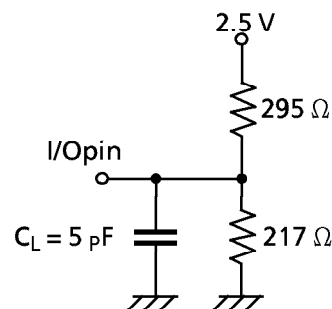
**AC TEST CONDITIONS**

|                                           |                               |
|-------------------------------------------|-------------------------------|
| Input Pulse Level                         | 2.3 V/0.0 V                   |
| Input Pulse Rise and Fall Time            | 1 V/ns(20%/80%)               |
| Input Timing Measurement Reference Level  | 1.15 V                        |
| Output Timing Measurement Reference Level | 1.15 V                        |
| Output Load                               | As shown in Fig. 1 and Fig. 2 |

**Fig. 1 : AC test load**



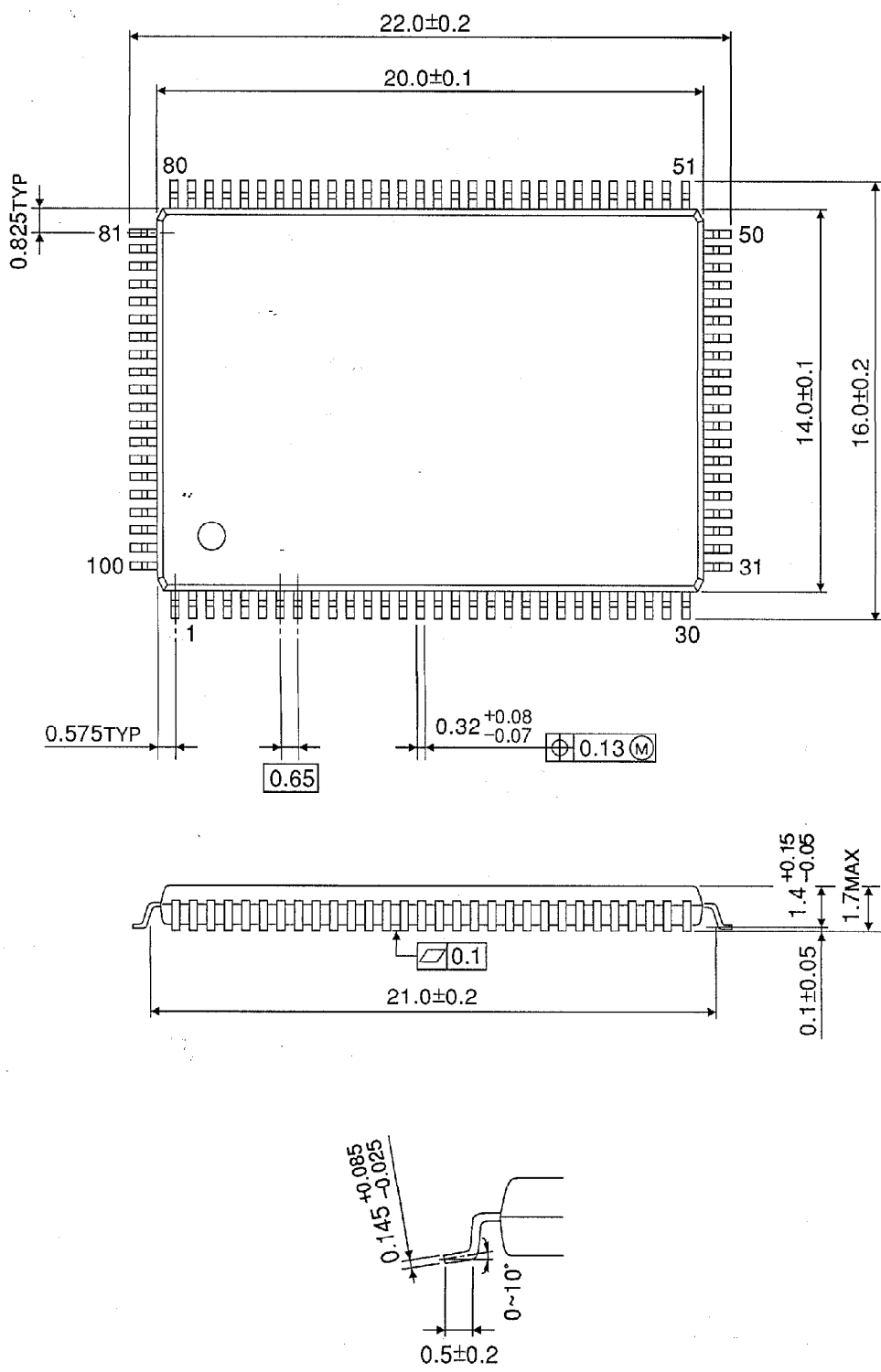
**Fig. 2 : AC test load (for Enable/Disable spec)**



PACKAGE DIMENSIONS

Plastic LQFP (LQFP100-P-1420-0.65K)

Unit: mm



Weight: 0.56 g (typ.)